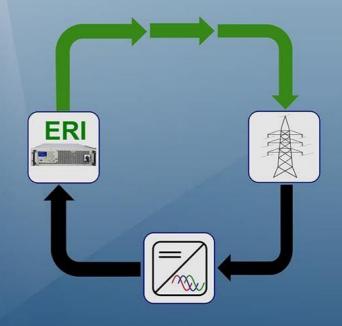


能量反馈式电子负载 ERI 系列



3,600 W to 10,800 W 120 V to 800 V 22.5 A to 330 A



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为什么要选购带有能量反馈的电子负载?

能量回收优于浪费热量 有利于环境保护 节约电能费用 生态型能源利用

> 改善实验室环境 减少空调使用 无风扇噪音



Electronic Energy Recycling Load ERI Series

SCPI Syntax	
Interface Overview RS-232 X USB X LAN X GPIB O CAN X Analog X Analog isolated O X Standard O Option / not available	·
 Energy feedback into the local power grid Low heat waste - silent - lab operation 	ly to USB mass storage device ons for voltage and current

- CC CV CR CP CCV CVC mode
- Ethernet + USB + RS-232 + CAN + I/O Port as standard

Functions

- SCPI Programming with measurement function
- Dynamic loads with synchronized DAQ

Electronic protection

ground loops and allows loading

of bipolar voltages with two

loads and common analog con-

trol.

- Digital Input and programmable output
- Galvanically isolated fast I/O Port (optional) ۲

Description **Loading Capacity** Cooling ERI Series Electronic Loads feed The units provide constant cur-The type spectrum contains 3 ERI loads recover the consumed the consumed energy with an rent, constant voltage, constant power classes from 3,600 W to energy instead of converting to efficiency of up to 95 % back into 10,800 W and input voltages resistance and constant power thermal energy. the local power grid. of 120 V, 400 V and 800 V. mode. Thus, electricity costs are reduced The devices offer an extensive In addition, protections for curand the environment is only variety of standard interfaces. rent and voltage can be set in slightly warmed. As a conse-Protections and Messages any mode. Dynamic operation quence, in many cases air-Apart from Ethernet, USB, RS-232 can be configured by up to 300 condition is unnecessary. • Current protection and a fast I/O Port there is a list point settings. standard CAN interface. Power protection Energy recycling loads do not A data acquisition function al-• Overtemperature protecneed powerful fans. That makes GPIB can be installed as an option tion lows to store measurement data the devices acceptably quiet and (ERI02). on an external USB flash drive. Overvoltage indication therefore perfectly fit for laborato-Programming is done in SCPI with Reverse polarity indication ry operation. an extensive command syntax. Protection of the GND lines at the I/O Port Interfaces I/O Port Galvanically Isolated I/O Port (Option FCC-ERIxx) The following interfaces are in-Standard I/O Port for the follo-(Option ERI06) cluded as standard: wing functions: For the galvanic isolation be-• Ethernet Load setting C and V tween the I/O Port and the load USB Analog setting of C and V terminals the ERI06 option can • RS-232 protections be installed. CAN Load on-off Using this board prevents • I/O Port Voltage monitor output

LabVIEW driver is certified by National Instruments.



• Digital input • Programmable control output

• Current monitor output

Trigger input

Trigger output

Factory Calibration Certificate

A Factory Calibration Certificate (FCC) can be supplied with the devices. The FCC meets the requirements according to DIN EN ISO 9000ff. This calibration certificate documents the traceability to national standards to illustrate the physical device in accordance with the international System of Units (SI).

The recommended calibration interval is 2 years.

Mechanics / Terminals



Mechanics

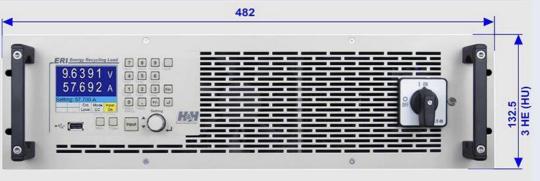
The ERI load has a sturdy 19" rack design and can also be used as a table-top device. No additional mounting kits are needed for 19" rack installation.

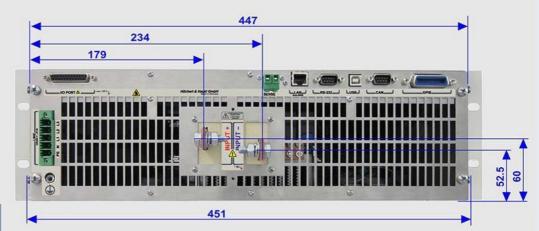
Terminals

All connections are located at the rear side. The current terminals are designed as solid copper bars.

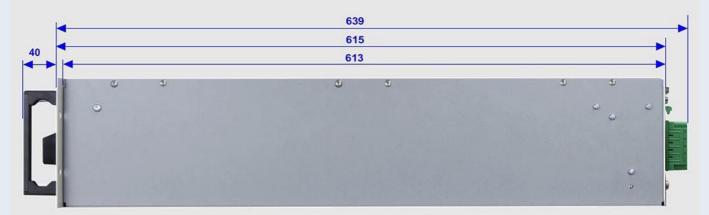
Safety

Covers are supplied as touch protection for units operating with dangerous contact voltages.









Data Acquisition / Dynamic Functions / Tools

Data Acquisition

Dynamic Function

can be generated.

Settings Memory

The standard Data Acquisition function expands the possibilities of the device by the following items:

In CC, CV, CR and CP mode, complex load profiles can be realized by List function. 300 load levels with a corresponding ramp and dwell time

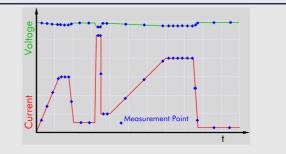
To permanently save device settings 2 user memories are available. Furthermore, the last settings at power off can be reloaded when the load is powered on. At power on the Electronic Load can either set reset values, the last active settings at power off or setting memory 1 or 2.

- Storing measurement data to external USB flash drive (timestamp, voltage and current)
- Fast synchronized data logging with internal data memory for waveform generation (timestamp, voltage and current)



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Example: Data logging with constant sampling rate



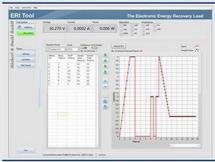
Example: Waveform generated by List function with synchronized recording of measured values of time, voltage and current.



Software Tool

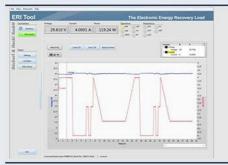
The ERI Tool is a graphical software tool to control the ERI series Electronic Loads. The user can choose different functions with the aid of the navigation bar.

The most important load settings are done in the Main Menu ("Settings"). Several graphical widgets inform the user about the measurements and the current device status. Further on, a data logging function can be activated in the Main Menu.



List Editor

The list editor is used to create dynamic load profiles for current, voltage, resistance, or power with the corresponding ramp and dwell times. Additionally, a synchronous sampling rate for current and voltage measurements can be individually set for each interpolation point. The generated list profile can be sent directly to the load via one of the data interfaces or saved to a data storage for further processing.



Data Viewer

Measurement values of the internal DAQ memory can be exported from the Electronic Load and displayed as a diagram with the aid of the "Data Viewer". The measurement data can also be saved on a data storage as a *.CSV file for further processing.



Model Overview 3,600 W ... 10,800 W DC

Model (order number)	ERI3612	ERI3640	ERI3680
Maximum input voltage	120 V	400 V	800 V
Current	110 A	45 A	22.5 A
Continuous power	3,600 W	3,600 W	3,600 W
Voltage setting	0 120 V	0 400 V	0 800 V
Current setting	0 110 A	0 45 A	0 22.5 A
Resistance setting	18.8 mΩ 11.731 Ω	44.4 mΩ 95.58 Ω	88.9 mΩ 382 Ω
Power setting	0 3,600 W	0 3,600 W	0 3,600 W
Rise/fall time ¹⁾	200 µs	200 µs	200 µs
Input capacity	350 µF	200 µF	150 µF
Minimum input voltage ²⁾	3 V	3 V	3 V
Mains ³⁾	230 VAC L->N / 50 Hz	230 VAC L->N / 50 Hz	230 VAC L->N / 50 Hz
Power consumption ⁴⁾	35 VA	55 VA	75 VA
Efficiency ⁵⁾	95 %	90 %	90 %
Maximum Noise ⁶⁾	55 dB(A)	57 dB(A)	60 dB(A)
Load terminals ⁷⁾	FKS20/4-SM8	FKS20/4-SM8	FKS20/4-SM8
Weight	17 kg	17 kg	17 kg
Housing ⁸⁾ W x H x D (mm)	482 x 133 x 679	482 x 133 x 679	482 x 133 x 679
Height / installation depth (mm)	19", 3 HU / 637	19", 3 HU / 637	19", 3 HU / 637

Model (order number)	ERI7212	ERI7240	ERI7280
Maximum input voltage	120 V	400 V	800 V
Current	220 A	90 A	45 A
Continuous power	7,200 W	7,200 W	7,200 W
Voltage setting	0 120 V	0 400 V	0 800 V
Current setting	0 220 A	0 90 A	0 45 A
Resistance setting	9.09 mΩ 5.865 Ω	22.2 mΩ 47.79 Ω	44.4 mΩ 191 Ω
Power setting	0 7,200 W	0 7,200 W	0 7,200 W
Rise/fall time ¹⁾	200 µs	200 µs	200 µs
Input capacity	700 µF	400 µ	300 µF
Minimum input voltage ²⁾	3 V	3 V	3 V
Mains ³⁾	400 VAC L->L / 50 Hz	400 VAC L->L / 50 Hz	400 VAC L->L/50 Hz
Power consumption ⁴⁾	35 VA	55 VA	75 VA
Efficiency ⁵⁾	95 %	90 %	90 %
Maximum Noise ⁶⁾	60 dB(A)	62 dB(A)	64 dB(A)
Load terminals ⁷⁾	FKS20/4-SM8	FKS20/4-SM8	FKS20/4-SM8
Weight	28 kg	28 kg	28 kg
Housing ⁸⁾ W x H x D (mm)	482 x 133 x 679	482 x 133 x 679	482 x 133 x 679
Height / installation depth (mm)	19", 3 HU / 637	19", 3 HU / 637	19", 3 HU / 637

Model (order number)	ERI10812	ERI10840	ERI10880
Maximum input voltage	120 V	400 V	800 V
Current	330 A	135 A	67.5 A
Continuous power	10,800 W	10,800 W	10,800 W
Voltage setting	0 120 V	0 400 V	0 800 V
Current setting	0 330 A	0 135 A	0 67.5 A
Resistance setting	6.06 mΩ 3.910 Ω	14.8 mΩ 31.86 Ω	29.6 mΩ 127 Ω
Power setting	0 10,800 W	0 10,800 W	0 10,800 W
Rise/fall time ¹⁾	200 µs	200 µs	200 µs
Input capacity	1050 μF	600 µF	450 μF
Minimum input voltage ²⁾	3 V	3 V	3 V
Mains ³⁾	400 VAC L->L / 50 Hz	400 VAC L->L / 50 Hz	400 VAC L->L / 50 Hz
Power consumption ⁴⁾	35 VA	55 VA	75 VA
Efficiency ⁵⁾	95 %	90 %	90 %
Maximum Noise ⁶⁾	60 dB(A)	62 dB(A)	64 dB(A)
Load terminals ⁷⁾	FKS20/4-SM8	FKS20/4-SM8	FKS20/4-SM8
Weight	37 kg	37 kg	37 kg
Housing ⁸⁾ W x H x D (mm)	482 x 133 x 679	482 x 133 x 679	482 x 133 x 679
Height / installation depth (mm)	19", 3 HU / 637	19", 3 HU / 637	19", 3 HU / 637

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2) Minimum input voltage for maximum load current
3) 230 / 400 VAC +10 % -15 %, 50Hz
1-phase at 3.6 kW

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2-phase at 7.2 kW 3-phase at 10.8 kW Power consumption in idle operation (without load current)
 Maximum achievable efficiency

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5) Maximum achievable efficiency6) Measured at the from in distance of 1 m

7) Flat copper bar 20 x 4 mm vertically installed with screw M8

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8) Greatest width and depth without wiring 1 HU = 44.45 mm

Subject to modification without notice, errors and omissions expected

Technical	Data	ERI Series
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Accuracy of setting			
	of the corresponding r	ange	
Current	±0.3 %		
Voltage	±0.3 %		
Resolution	14 bit		
Accuracy of protection	ons		
	of the corresponding r	ange	
Overcurrent	±0.5 %		
protection			
Undervoltage protection	±0.5 %		
Resolution	12 bit		
Accuracy of measure			
(in static CC, CR, CV			
	of the corresponding r	ange	
Voltage	±0.1 %		
Current	±0.3 %		
Resistance	is calculated from volt	age and current	
Power	is calculated from volt	age and current	
Resolution	18 bit		
Sampling rate	330 ms, not triggerab	le	
Accuracy of measure	ment/display		
(in static CP mode ar	nd all dynamic modes)	
	of the corresponding r	ange	
Voltage	±0.3 %		
Current	±0.5 %		
Resistance	is calculated from volt	age and current	
Power	is calculated from volt	age and current	
Resolution	12 bit		
Sampling rate	200 μs 800,000 s		
oumpring rate	200 µs 800,000 s		
Dynamic Function (L			
Dynamic Function (L Number of load	IST)	ime and dwell time setting	
Dynamic Function (L	IST) max. 300, with ramp t	-	
Dynamic Function (L Number of load levels	IST) max. 300, with ramp f min.	max.	
Dynamic Function (L Number of load levels Dwell time	IST) max. 300, with ramp f min. 200 µs	max. 800000 s	
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Accuracy of analog mea	surement outputs 0	10 V for voltage, current	
	of analog signal of	offset voltage	
Malla an	real value		
Voltage Current	±0.2 % ±0.4 %	±15 mV ±15 mV	
Minimum load 2 kΩ	-0.4 //	113 1114	
*) 125 V with option ERI06			
I/O Port outputs and in			
Outputs Output level	status load on - off status overload (OV, OCP, OPP, OTP) trigger output programmable output selectable, 3.3 V, 5 V, 12 V, or externally programmable up to 30 V		
Inputs Input level	load on-off mode selection trigger input programmable input control input remote shut-down		
Input			
Input resistance	>50 kΩ when load in Diode function at rev current	nput is off rerse polarity up to nominal	
Input capacity	siehe Modellübersich	t	
Permissible operating voltage	negative load input - 125 V DC	housing	
Power	see model overview		
Derating	-2 %/°C for T _A > 21	°C	
Protection and monitor Protective devices			
Protective devices	overcurrent overpower overtemperature		
Monitoring signals	overvoltage indication undervoltage indication (if the input voltage is too low for the set current) reverse polarity indication		
Operating conditions			
Operating temperature	5 °C 40 °C		
Cooling	air-cooling		
Mains voltage and power consumption	see model overview		
Housing			
Color front panel rear panel top Dimensions	RAL7037 (stone grey		
Safety and EMC			
Protection	IP20		
Measuring category			
Electrical safety	O (CAT I according to EN61010 Rev. 2004) DIN EN 61010		
EMC, CE marking	DIN EN 55011 DIN EN 61326-1 DIN EN 61000-3-2 DIN EN 61000-3-3		
Available options			
Data interface ERI02	GPIB Interface		
Hardware expansion ERI06	Galvanically isolated 1	I/O Port	
Kalibrierung			
FCC-N-ERIxx FCC-ERIxx	Factory Calibration Ce Factory Calibration Ce	ertificate for new devices ertificate	